

SPEC SHEET (FOR REFERENCE)	SHEET No.	Rev.	Page.
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TYPE:6PT1602P1T* *	
CHIP SIZE	0.36 * 0.36mm
WAFER SIZE	6 inch

Maximum Ratings (Ta=25°C)

Characteristics	Symbol	Ratings	Unit
Drain-Source voltage	VDSS	-20	V
Gate-Source voltage	VGSS	±8	V

WAFER PROBING SPEC (Ta=25°C)

No	MODE	LIMIT			UNIT	CONDITIONS
		MIN.	Typ	MAX.		
1	IGSS			±1	uA	VGS=±8V, VDS=0V
2	IDSS			-10	uA	VDS=-22V, VGS=0V
3	BVDSS	-22			V	ID=-100uA, VGS=0V
4	Vth	-0.65		-1.05	V	ID=-250uA, VGS=VDS
5	RDS(on)		2.2	3.6	Ω	VGS=-4.0V, ID=-100mA
6	Yfs	130			mS	VDS=-10V, ID=-100mA

※Built in ZD between Gate and Source

PHENITEC SEMICONDUCTOR Corp.